

HS-C²MOS™ INTEGRATED CIRCUITS



PRELIMINARY DATA

OCTAL COUNTER/DIVIDER

DESCRIPTION

The M54/74HC4022 is a high speed CMOS OCTAL COUNTER/DIVIDER fabricated in silicon gate C²MOS technology.

It has the same high speed performance of LSTTL combined with true CMOS low power consumption. It contains a 4-stage divide-by-8 Johnson counter with 8 decoded outputs (Q0-Q7) and a Carry-out bit. This counter is advanced on the positive edge of clock signal when CLOCK ENABLE input is held low, or is advanced on the negative edge of clock enable signal when CLOCK input is held high, and the selected one of eight outputs goes high. Holding high the CLEAR input, this counter is cleared to its zero state without regard to the other input conditions. All inputs are equipped with protection circuits against static discharge or transient excess voltage.

B1 Plastic Package **F1** Ceramic Package **C1** Chip Carrier

ORDERING NUMBERS: M54HC4022 F1
M74HC4022 B1
M74HC4022 F1
M74HC4022 C1

FEATURES

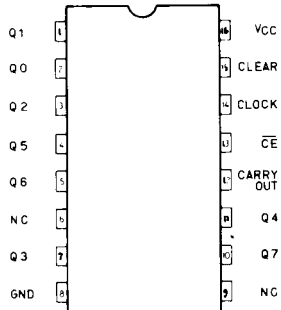
- High Speed
 $f_{MAX} = 42 \text{ MHz (Typ) at } V_{CC} = 5V$
- Low Power Dissipation
 $I_{CC} = 4 \mu A \text{ (Max.) at } T_A = 25^\circ C$
- High Noise Immunity
 $V_{NIH} = V_{NIL} = 28\% V_{CC} \text{ (Min.)}$
- Output Drive Capability
10 LSTTL Loads
- Symmetrical Output Impedance
 $|I_{OH}| = I_{OL} = 4 \text{ mA (Min.)}$
- Balanced Propagation Delays
 $t_{PLH} = t_{PHL}$
- Wide Operating Voltage Range
 $V_{CC} \text{ (opr)} = 2V \text{ to } 6V$
- Pin and Function compatible with 4022B

TRUTH TABLE

X: Don't Care

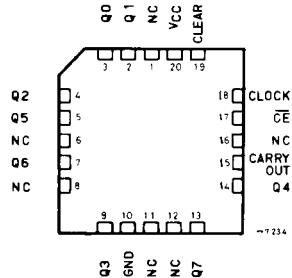
CLOCK	CE	CLEAR	DECODER OUTPUT(H)
X	X	H	Q0
L	X	L	No Change
X	H	L	No Change
\downarrow	L	L	No Change + 1
\uparrow	L	L	No Change
H	\downarrow	L	No Change
H	\uparrow	L	No Change + 1

PIN CONNECTIONS (top view)



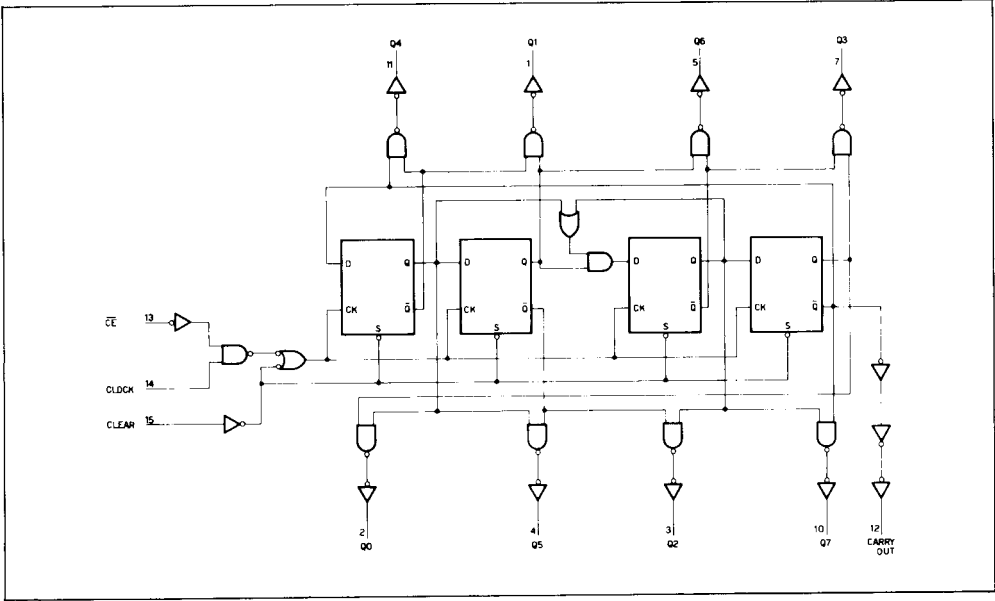
Dual in line

CHIP CARRIER

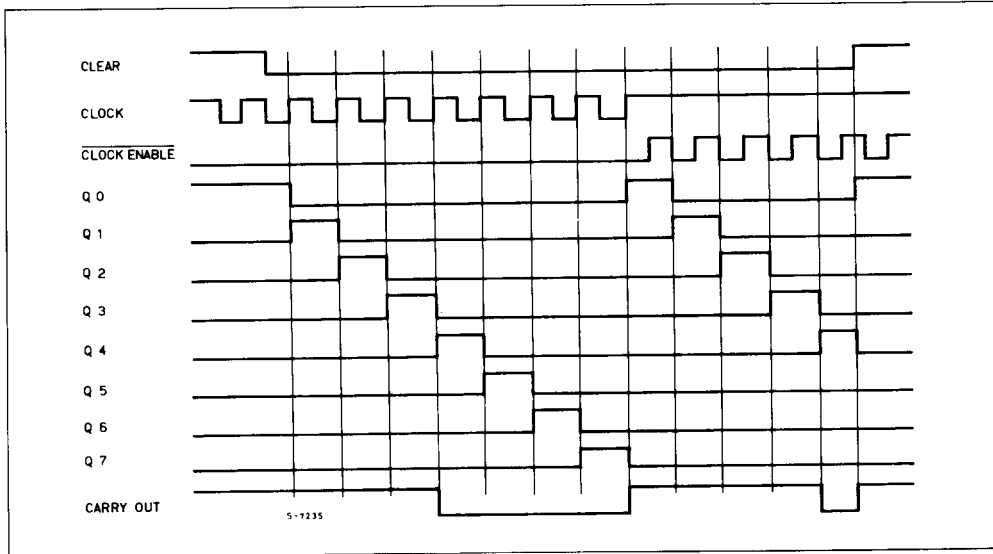


NC = No Internal Connection

LOGIC DIAGRAM



TIMING CHART





ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	-0.5 to 7	V
V_I	DC Input Voltage	-0.5 to $V_{CC} + 0.5$	V
V_O	DC Output Voltage	-0.5 to $V_{CC} + 0.5$	V
I_{IK}	DC Input Diode Current	± 20	mA
I_{OK}	DC Output Diode Current	± 20	mA
I_O	DC Output Source Sink Current Per Output Pin	± 25	mA
I_{CC} or I_{GND}	DC V_{CC} or Ground Current	± 50	mA
P_D	Power Dissipation	500 (*)	mW
T_{stg}	Storage Temperature	-65 to 150	$^{\circ}C$

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

(*) 500 mW: \cong 65 $^{\circ}C$ derate to 300 mW by 10 mW/ $^{\circ}C$: 65 $^{\circ}C$ to 85 $^{\circ}C$.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Limit	Unit
V_{CC}	Supply Voltage	2 to 6	V
V_I	Input Voltage	0 to V_{CC}	V
V_O	Output Voltage	0 to V_{CC}	V
T_A	Operating Temperature 74HC Series 54HC Series	-40 to 85 -55 to 125	$^{\circ}C$
t_r, t_f	Input Rise and Fall Time	$V_{CC} \begin{cases} 2 \text{ V} & 0 \text{ to } 1000 \\ 4.5 \text{ V} & 0 \text{ to } 500 \\ 6 \text{ V} & 0 \text{ to } 400 \end{cases}$	ns

DC SPECIFICATIONS

Symbol	Parameter	V_{CC}	Test Condition	$T_A = 25^{\circ}C$			-40 to 85 $^{\circ}C$		-55 to 125 $^{\circ}C$		Unit
				54HC and 74HC			74HC		54HC		
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
V_{IH}	High Level Input Voltage	2.0		1.5	—	—	1.5	—	1.5	—	V
		4.5		3.15	—	—	3.15	—	3.15	—	
		6.0		4.2	—	—	4.2	—	4.2	—	
V_{IL}	Low Level Input Voltage	2.0		—	—	0.5	—	0.5	—	0.5	V
		4.5		—	—	1.35	—	1.35	—	1.35	
		6.0		—	—	1.8	—	1.8	—	1.8	



M54HC4022
M74HC4022

DC SPECIFICATIONS (Continued)

Symbol	Parameter	V _{CC}	Test Condition		T _A = 25°C 54HC and 74HC			- 40 to 85°C 74HC		- 55 to 125°C 54HC		Unit
					Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
V _{OH}	High Level Output Voltage	2.0	V _I	I _O	1.9	2.0	—	1.9	—	1.9	—	V
		4.5	V _{IH}	-20 μA	4.4	4.5	—	4.4	—	4.4	—	
		6.0	or		5.9	6.0	—	5.9	—	5.9	—	
		4.5	V _{IL}	-4.0 mA	4.18	4.31	—	4.13	—	4.10	—	
		6.0		-5.2 mA	5.68	5.8	—	5.63	—	5.60	—	
V _{OL}	Low Level Output Voltage	2.0	V _{IH}	20 μA	—	0	0.1	—	0.1	—	0.1	V
		4.5			—	0	0.1	—	0.1	—	0.1	
		6.0	V _{IL}	4.0 mA	—	0	0.1	—	0.1	—	0.1	
		4.5			4.0 mA	—	0.17	0.26	—	0.33	—	
		6.0		5.2 mA	—	0.18	0.26	—	0.33	—	0.40	
I _I	Input Leakage Current	6.0	V _I = V _{CC} or GND		—	—	±0.1	—	±1		±1	μA
I _{CC}	Quiescent Supply Current	6.0	V _I = V _{CC} or GND		—	—	4	—	40		80	μA

AC ELECTRICAL CHARACTERISTICS (V_{CC} = 5V, T_A = 25°C, C_L = 15pF, Input t_r = t_f = 6ns)

Symbol	Parameter	54HC and 74HC			Unit
		MIN.	TYP.	MAX.	
t _{TLH} t _{THL}	Output Transition Time		4	8	ns
t _{PLH} t _{PHL}	Propagation Delay Time (CLOCK-Q, CARRY)		21	33	ns
t _{PLH} t _{PHL}	Propagation Delay Time (CLEAR-Q, CARRY)		21	33	ns
f _{MAX}	Maximum Clock Frequency	30	48		ns
t _{W(L)} t _{W(H)}	Minimum Pulse Width (CLOCK)		8	15	ns
t _{W(H)}	Minimum Pulse Width (CLEAR)		9	15	ns
t _s	Minimum Set-up Time		—	0	ns
t _h	Minimum Hold Time		9	15	ns
t _{REM}	Minimum Removal Time		8	15	ns

AC ELECTRICAL CHARACTERISTICS ($C_L = 50\text{pF}$, Input $t_r = t_f = 6\text{ns}$)

Symbol	Parameter	V _{CC}	Test Condition	T _A = 25°C 54HC and 74HC			-40 to 85°C 74HC		-55 to 125°C 54HC		Unit
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
t _{TLH} t _{THL}	Output Transition Time	2.0		—	30	75	—	90			ns
		4.5		—	9	15	—	18			
		6.0		—	8	13	—	16			
t _{PLH} t _{PHL}	Propagation Delay Time (CLOCK-Q, CARRY)	2.0		—	100	195	—	235			ns
		4.5		—	25	39	—	47			
		6.0		—	22	34	—	40			
t _{PLH} t _{PHL}	Propagation Delay Time (CLEAR-Q, CARRY)	2.0		—	100	195	—	235			ns
		4.5		—	25	39	—	47			
		6.0		—	22	34	—	40			
f _{MAX}	Maximum Clock Frequency	2.0		5	10	—	4	—			MHz
		4.5		25	40	—	20	—			
		6.0		29	45	—	23	—			
t _{W(L)} t _{W(H)}	Minimum Pulse Width (CLOCK)	2.0		—	30	75	—	90			ns
		4.5		—	8	15	—	18			
		6.0		—	7	13	—	16			
t _{W(H)}	Minimum Pulse Width (CLEAR)	2.0		—	35	75	—	90			ns
		4.5		—	9	15	—	18			
		6.0		—	8	13	—	16			
t _s	Minimum Set-up Time	2.0		—	—	0	—	0			ns
		4.5		—	—	0	—	0			
		6.0		—	—	0	—	0			
t _h	Minimum Hold Time	2.0		—	35	75	—	90			ns
		4.5		—	9	15	—	18			
		6.0		—	8	13	—	16			
t _{REM}	Minimum Removal Time	2.0		—	30	75	—	90			ns
		4.5		—	8	15	—	18			
		6.0		—	7	13	—	16			
C _{IN}	Input Capacitance			—	5	10	—	10			pF
C _{PD} (*)	Power Dissipation Capacitance			—	52	—	—	—			pF

Note (*) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the following equation.

$$I_{CC(\text{opr})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$